

Features

- Very Low FOM $R_{DS(on)} \times Q_g$
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

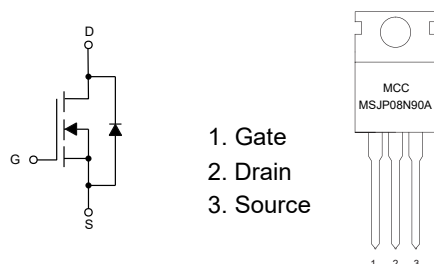
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 34°C/W Junction to Ambient^(Note 2)
- Thermal Resistance: 1.1°C/W Junction to Case

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DS}	900	V
Gate-Source Voltage	V_{GS}	±30	V
Continuous Drain Current	I_D	8	A
		5	
		$T_C=25^\circ\text{C}$	
		$T_C=100^\circ\text{C}$	
Pulsed Drain Current ^(Note 3)	I_{DM}	32	A
Total Power Dissipation ^(Note 4)	P_D	114	W
Single Pulsed Avalanche Energy ^(Note 5)	E_{AS}	81	mJ

Note:

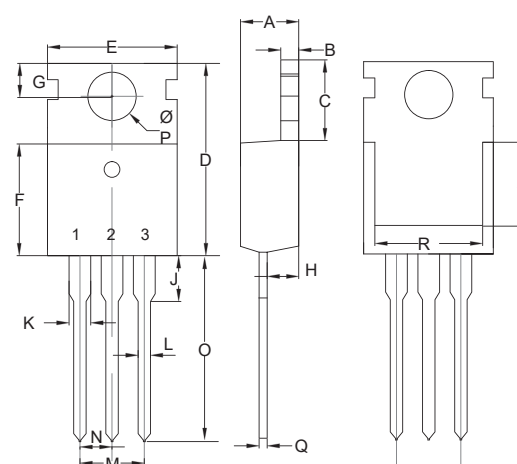
1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. The value of $R_{\theta JA}$ is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with $T_C=25^\circ\text{C}$.
3. Repetitive rating; pulse width limited by max. junction temperature.
4. P_D is based on max. junction temperature, using junction-case thermal resistance.
5. $T_J=25^\circ\text{C}$, $V_{DD}=50\text{V}$, $V_G=10\text{V}$, $R_G=25\Omega$, $L=50\text{mH}$

Internal Structure and Marking Code



N-CHANNEL Super-Junction Power MOSFET

TO-220AB(H)



DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.169	0.185	4.30	4.70	
B	0.049	0.055	1.25	1.40	
C	0.244	0.268	6.20	6.80	
D	0.598	0.638	15.20	16.20	
E	0.382	0.398	9.70	10.10	
F	0.354	0.370	9.00	9.40	
G	0.102	0.118	2.60	3.00	
H	0.087	0.102	2.20	2.60	
J	0.110	0.126	2.80	3.20	
K	0.048	0.055	1.22	1.40	
L	0.028	0.037	0.70	0.95	
M	0.188	0.212	4.78	5.38	
N	0.094	0.106	2.39	2.69	
O	0.496	0.535	12.60	13.60	
P	0.138	0.150	3.50	3.80	Φ
Q	0.016	0.024	0.40	0.60	
R	0.276	-----	7.00	-----	
S	0.217	-----	5.50	-----	

Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =250μA	900			V
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±30V			±100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =900V, V _{GS} =0V			1	μA
Gate-Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	2	3	4	V
Drain-Source On-Resistance	R _{DS(on)}	V _{GS} =10V, I _D =2.5A		1.1	1.62	Ω
Gate Resistance	R _g	f=1 MHz, Open drain		1.8		Ω
Diode Characteristics						
Continuous Body Diode Current	I _S				8	A
Body Diode Voltage	V _{SD}	I _S =11A, V _{GS} =0V			1.4	V
Reverse Recovery Time	t _{rr}	I _F =5A di/dt=100A/μs		304		ns
Reverse Recovery Charge	Q _{rr}			2246		nC
Dynamic Characteristics						
Input Capacitance	C _{iss}	V _{DS} =25V, V _{GS} =0V, f=1MHz		476		pF
Output Capacitance	C _{oss}			451		
Reverse Transfer Capacitance	C _{rss}			14		
Total Gate Charge	Q _g	V _{DS} =720V, I _D =5A V _{GS} =10V		16		nC
Gate-Source Charge	Q _{gs}			2.2		
Gate-Drain Charge	Q _{gd}			7.5		
Turn-On Delay Time	t _{d(on)}	V _{DD} =450V, V _{GS} =10V, I _D =5A R _G =25Ω		11		ns
Turn-On Rise Time	t _r			22		
Turn-Off Delay Time	t _{d(off)}			48		
Turn-Off Fall Time	t _f			23		

Curve Characteristics

Fig. 1 - Typical Output Characteristics

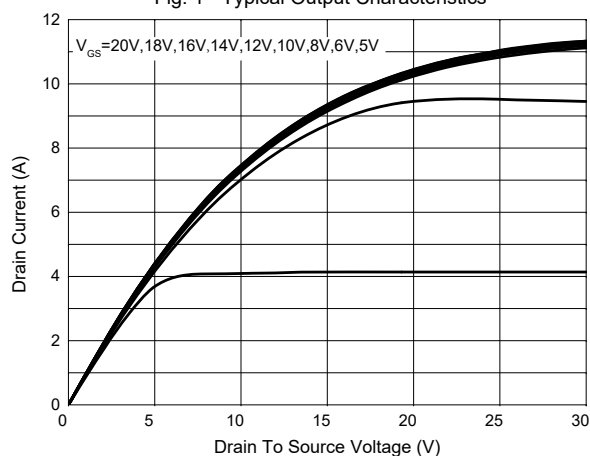


Fig.2 - Transfer Characteristic

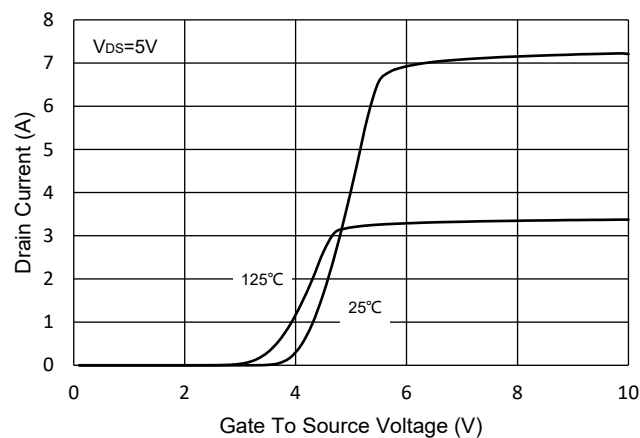


Fig.3 - $R_{DS(ON)} - V_{GS}$

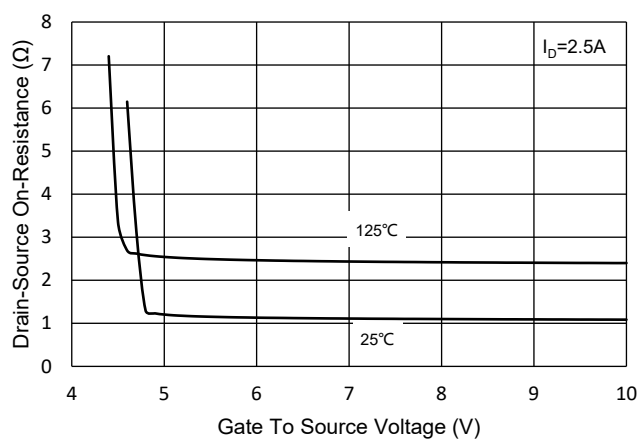


Fig. 4 - $R_{DS(ON)} - I_D$

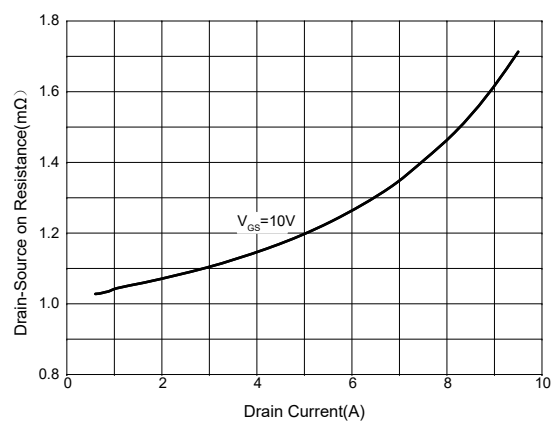


Fig.5 - Capacitance Characteristics

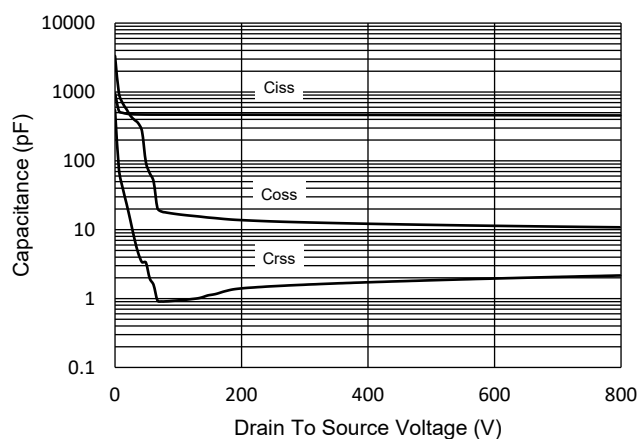
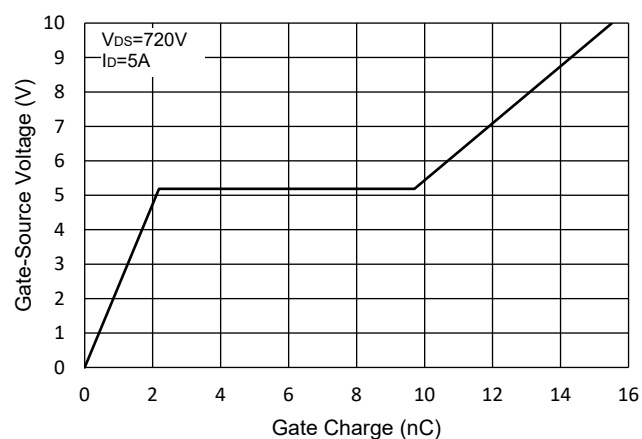


Fig.6 - Gate Charge



Curve Characteristics

Fig.7 - Normalized Threshold Voltage

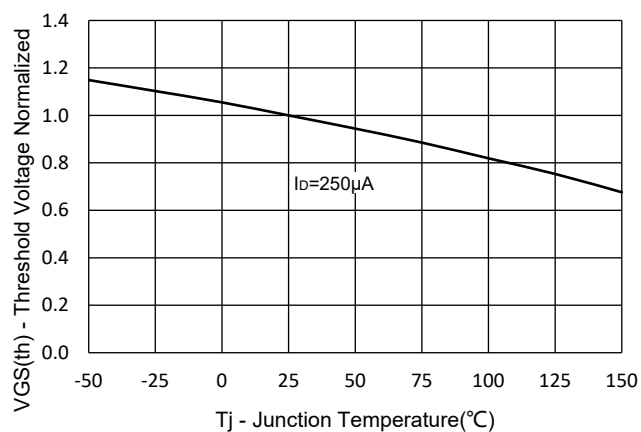


Fig.8 - Normalized On Resistance Characteristics

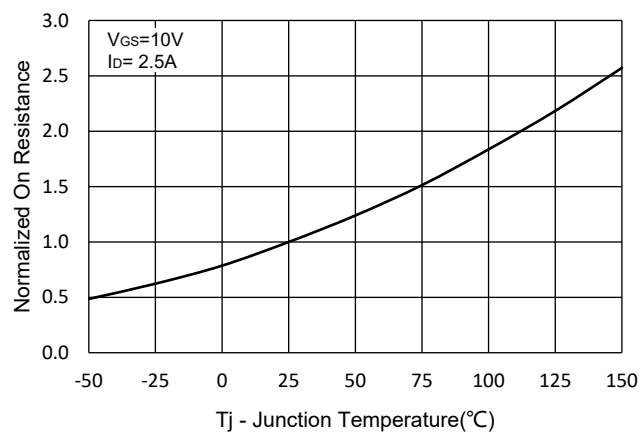


Fig.9 - $I_S - V_{SD}$

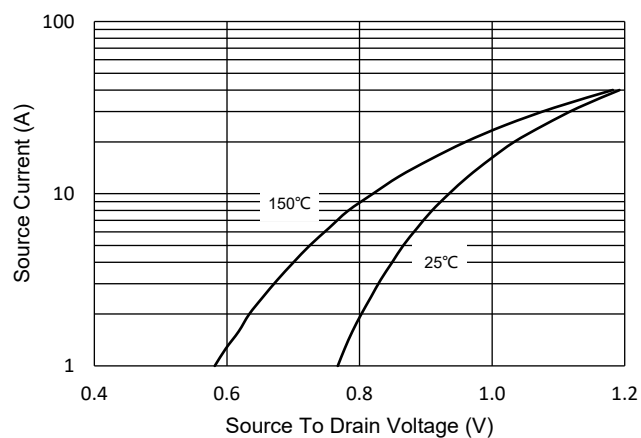


Fig.10 - Drain Current

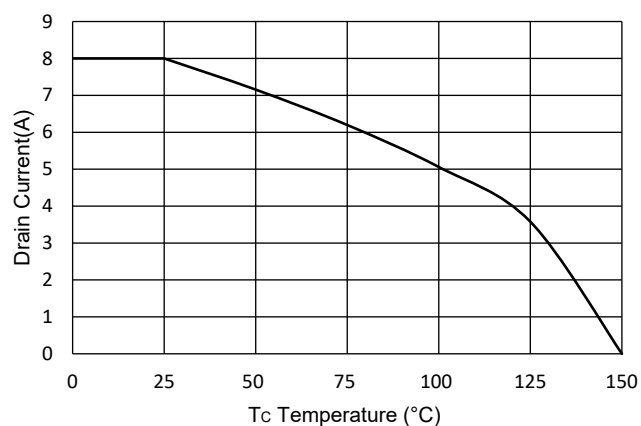
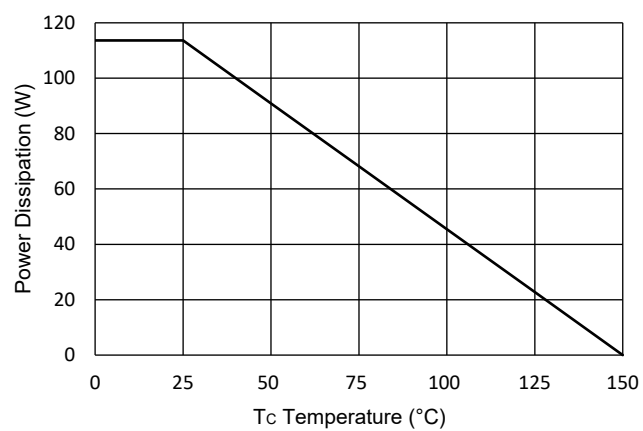


Fig.11 - PD Dissipation



Curve Characteristics

Fig.12 - Safe Operation Area

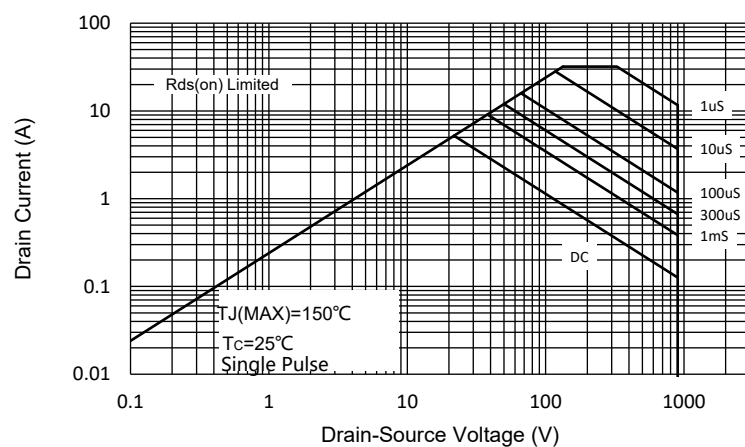
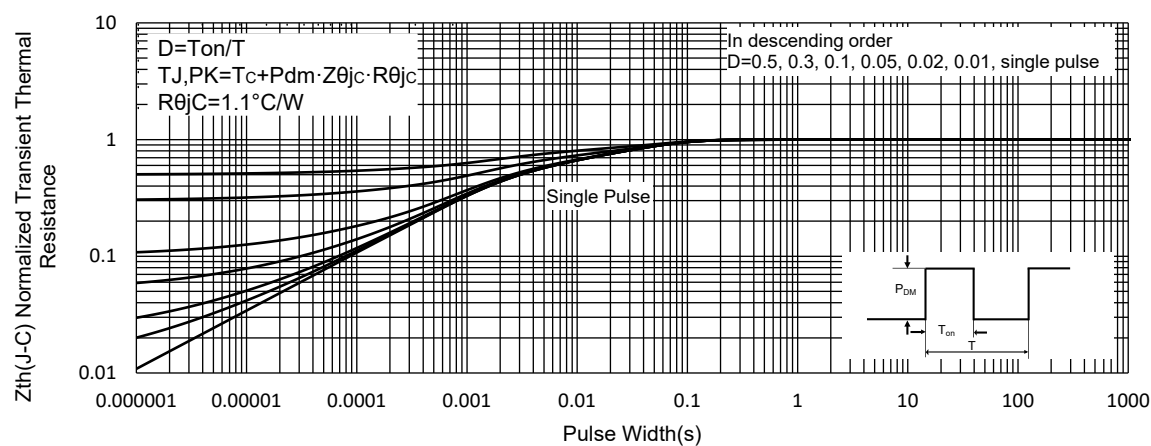


Fig.13 - Normalized Transient Thermal Impedance



Ordering Information

Device	Packing
Part Number-BP	Bulk:50pcs/Tube,1Kpcs/Box,5Kpcs/Carton

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